

Features

- High isolation 3750 V_{RMS}
- Multiple CTR selection available
- DC input with transistor output
- Operating temperature range 55 °C to 125 °C
- RoHS compliance
- REACH compliance
- Halogen compliance

Description

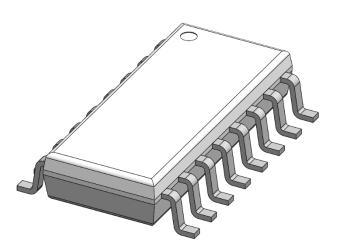
The CTH247 series have four isolated channels, each channel contains a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 16-lead half pitch Mini-Flat package.

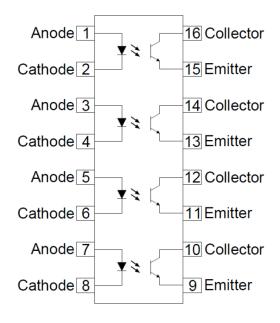
Applications

- DC-DC Converters
- Programmable controllers
- Telecommunication equipment
- Hybrid substrates that require high density mounting

Package Outline

Schematic







Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
Viso	Isolation voltage	3750	VRMS	1
T _{OPR}	Operating temperature	-55 ~ +125	°C	
T _{STG}	Storage temperature	-55 ~ +150	°C	
T _{SOL}	Soldering temperature	260	°C	2
Ртот	Total power dissipation	200	mW	
Emitter		·	·	
l _F	Forward current	50	mA	3
IF(TRANS)	Peak transient current (≤1µs P.W,300pps)	1	A	3
VR	Reverse voltage	6	V	3
PD	Power dissipation	70	mW	3
Detector	-	·	·	·
Pc	Power dissipation	100	mW	3
B _{VCEO}	Collector-Emitter Breakdown Voltage	80	V	3
BVECO	Emitter-Collector Breakdown Voltage	7	V	3
lc	Collector Current	50	mA	3

Notes

1. AC for 1 minute, $RH = 40 \sim 60\%$.

- 2. For reflow process
- 3. Each Channel



Electrical Characteristics T_A = 25°C, Each Channel (unless otherwise specified)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	IF=10mA		1.24	1.4	V	
I _R	Reverse Current	$V_R = 6V$	-	-	5	μΑ	
CIN	Input Capacitance	f= 1MHz	-	10	30	pF	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
BVCEO	Collector-Emitter Breakdown	Ic= 0.1mA	80	-	-	V	
B _{VECO}	Emitter-Collector Breakdown	I _E = 0.1mA	7	-	-	V	
ICEO	Collector-Emitter Dark Current	V _{CE} = 20V, I _F =0mA	-	-	100	nA	

Transfer Characteristics

Symbol	Parameter	rs	Test Conditions	Min	Тур	Max	Units	Notes
		CTH247		50		600		
CTR	Current Transfer	CTH247A	IF= 5mA, V _{CE} = 5V	80		160	%	
CIR	Ratio	CTH247B		130		260		
		CTH247C		200		400		
Maria	Collector-Emitter Satur	ation			0.1	0.2	V	
Vce(sat)	Voltage		I _F = 20mA, I _C = 1mA	-	0.1	0.2	V	
R _{IO}	Isolation Resistance		V_{IO} = 500 V_{DC}	5x10 ¹⁰			Ω	
Сю	Isolation Capacitance		f= 1MHz		0.5	1	pF	

Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
tr	Rise Time	$l_{1} = 2mA$ $V_{1} = 2V/B = 1000$	-	6	-	0	
t _f	Fall Time	I_{C} = 2mA, V_{CE} = 2V, R_{L} = 100 Ω	-	8	-	μs	



Test Circuit

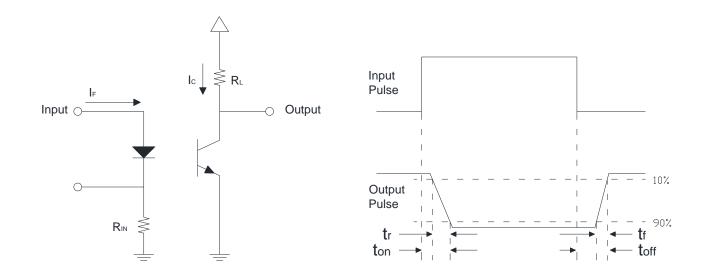
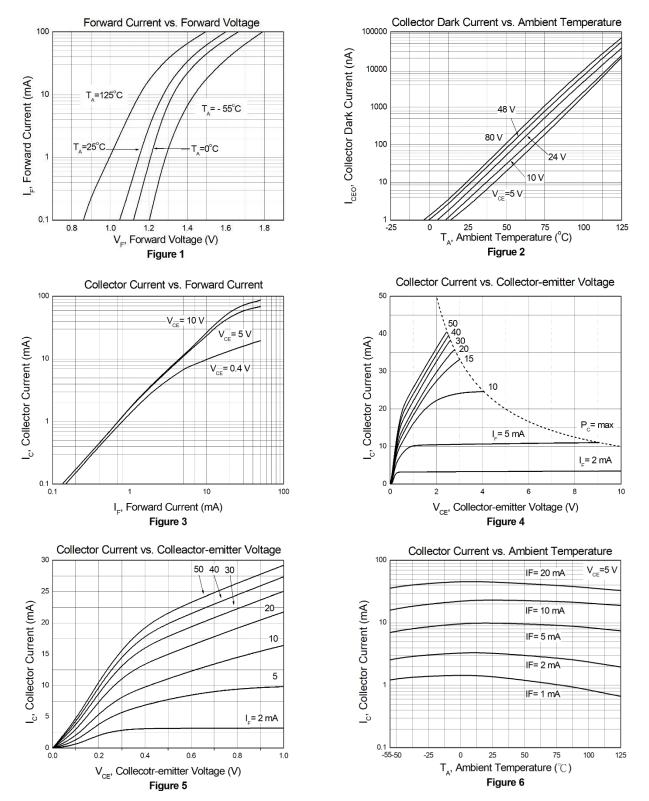


Figure 1: Switching Time Test Circuits



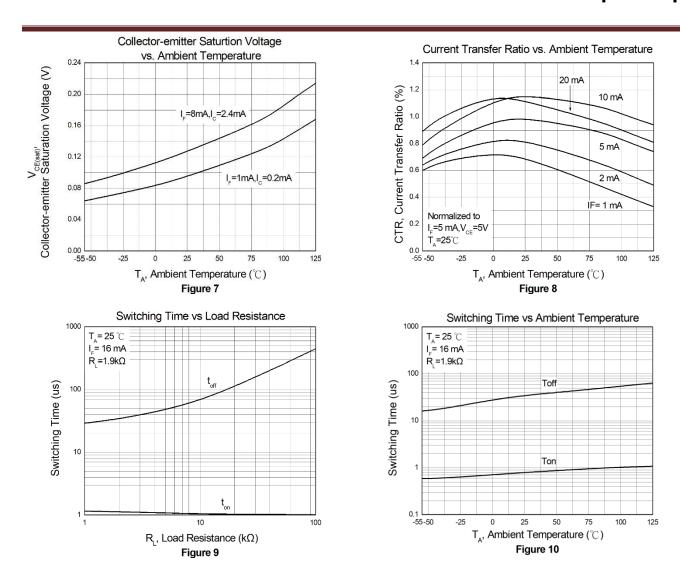
Typical Characteristic Curves





CTH247 Series

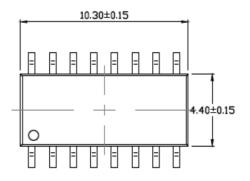
DC Input 16-Pin Half Pitch Mini-Flat Phototransistor Optocoupler

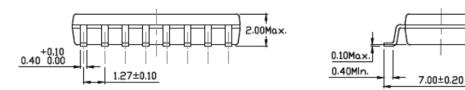




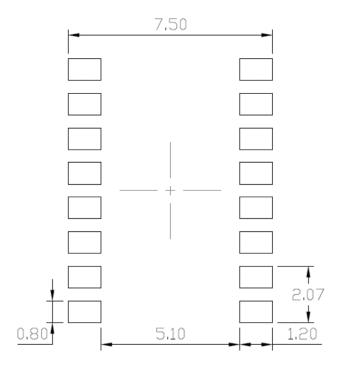
0.20±0.05

Package Dimension Dimensions in mm unless otherwise stated





Recommended Solder Mask Dimensions in mm unless otherwise stated





Marking Information



Note:

СТ	: Denotes "CT Micro"
247	: Product Number
Х	: CTR Rank
Y	: Fiscal Year
WW	: Work Week
К	: Manufacturing Code

Ordering Information

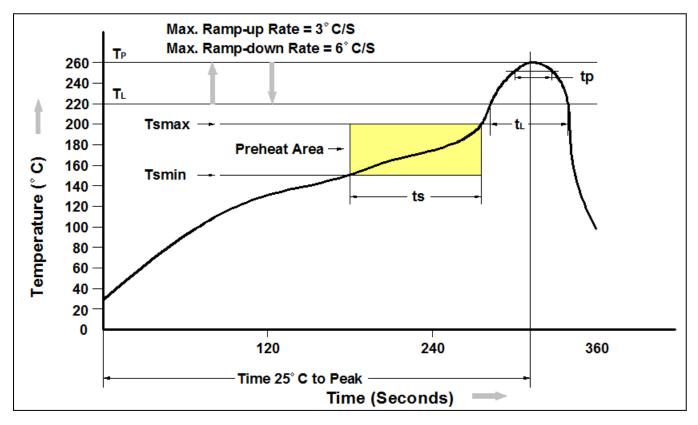
CTH247X(Z)

- CT = Denotes "CT Micro"
- H247 = Product Number
- X = CTR Rank (Blank, A, B or C)
- Z = Tape and reel option (T1, T2 or none)

Option	Description	Quantity
T1	Surface Mount Lead Forming – With Option 1 Taping	1000 Units/Reel
T2	Surface Mount Lead Forming – With Option 1 Taping	1000 Units/Reel



Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to tթ)	3°C/second max.
Liquidous Temperature (TL)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate $(T_P \text{ to } T_L)$	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



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